


BCR12CS

MEDIUM POWER USE

NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

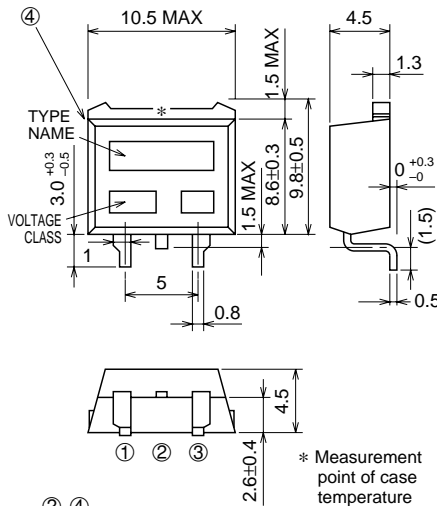
Refer to the page 6 as to the product guaranteed maximum junction temperature 150°C

BCR12CS



- **I_T (RMS)** **12A**
- **V_{DRM}** **600V**
- **IFGT I , IRGT I , IRGT III** **20mA**

OUTLINE DRAWING Dimensions in mm



④
10.5 MAX
1.5 MAX
4.5
1.3
3.0^{+0.3}_{-0.3}
TYPE NAME
VOLTAGE CLASS
1.5 MAX
8.6±0.3
9.8±0.5
5
0.8
0
+0.3
-0
(1.5)
0.5

① ② ③
4.5
2.6±0.4
* Measurement point of case temperature

② ④
① ③
① T1 TERMINAL
② T2 TERMINAL
③ GATE TERMINAL
④ T2 TERMINAL

TO-220S

APPLICATION

Contactless AC switches, light dimmer, electric flasher unit, control of household equipment such as TV sets · stereo · refrigerator · washing machine · infrared kotatsu · carpet · electric fan, solenoid drivers, small motor control, copying machine, electric tool, other general purpose control applications

MAXIMUM RATINGS

Symbol	Parameter	Voltage class		Unit
		12	600	
V _{DRM}	Repetitive peak off-state voltage *1	600		V
V _{DSM}	Non-repetitive peak off-state voltage *1	720		V

Symbol	Parameter	Conditions	Ratings	Unit
I _T (RMS)	RMS on-state current	Commercial frequency, sine full wave 360° conduction, T _c =98°C *3	12	A
I _{TSM}	Surge on-state current	60Hz sinewave 1 full cycle, peak value, non-repetitive	120	A
I ² _t	I ² _t for fusing	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	60	A ² s
P _{GM}	Peak gate power dissipation		5	W
P _G (AV)	Average gate power dissipation		0.5	W
V _{GM}	Peak gate voltage		10	V
I _{GM}	Peak gate current		2	A
T _j	Junction temperature		-40 ~ +125	°C
T _{stg}	Storage temperature		-40 ~ +125	°C
—	Weight	Typical value	1.2	g

*1. Gate open.

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Refer to the page 6 as to the product guaranteed maximum junction temperature 150°C

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ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit	
			Min.	Typ.	Max.		
IDRM	Repetitive peak off-state current	T _j =125°C, V _{DRM} applied	—	—	2.0	mA	
VTM	On-state voltage	T _c =25°C, I _{TM} =20A, Instantaneous measurement	—	—	1.6	V	
VFGT I	Gate trigger voltage *2	T _j =25°C, V _D =6V, R _L =6Ω, R _G =330Ω	I	—	—	1.5	V
VRGT I			II	—	—	1.5	V
VRGT III			III	—	—	1.5	V
IFGT I	Gate trigger current *2	T _j =25°C, V _D =6V, R _L =6Ω, R _G =330Ω	I	—	—	20	mA
IRGT I			II	—	—	20	mA
IRGT III			III	—	—	20	mA
VGD	Gate non-trigger voltage	T _j =125°C, V _D =1/2V _{DRM}	0.2	—	—	V	
Rth (j-c)	Thermal resistance	Junction to case *3 *4	—	—	1.8	°C/W	
(dv/dt) _c	Critical-rate of rise of off-state commutating voltage *5	T _j =125°C	10	—	—	V/μs	

*2. Measurement using the gate trigger characteristics measurement circuit.

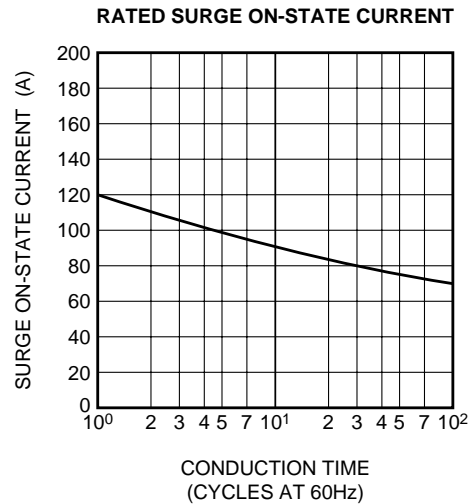
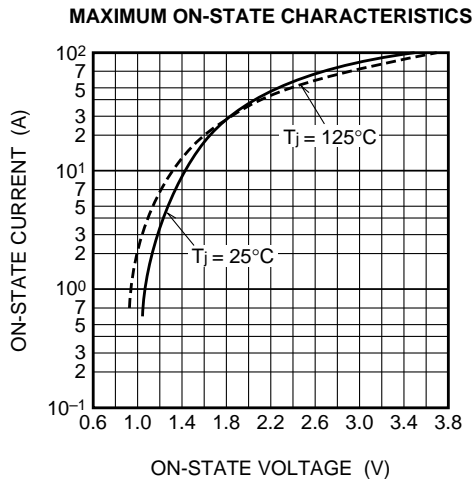
*3. Case temperature is measured on the T2 terminal.

*4. The contact thermal resistance Rth (c-f) in case of greasing is 1.0°C/W.

*5. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature T _j =125°C 2. Rate of decay of on-state commutating current (di/dt) _c =-6.0A/ms 3. Peak off-state voltage V _D =400V	

PERFORMANCE CURVES

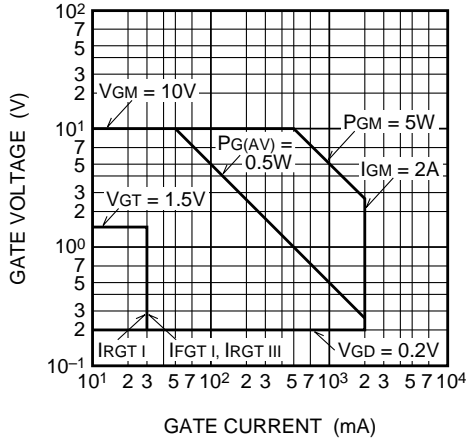


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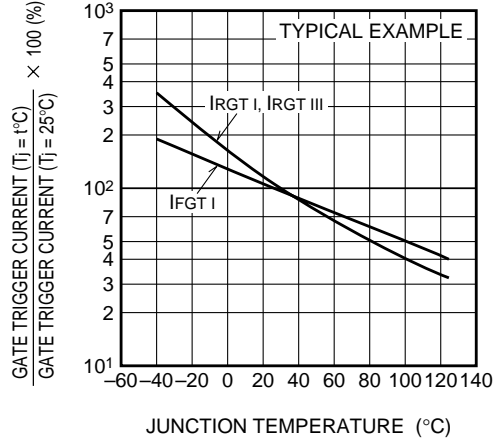
Refer to the page 6 as to the product guaranteed maximum junction temperature 150°C

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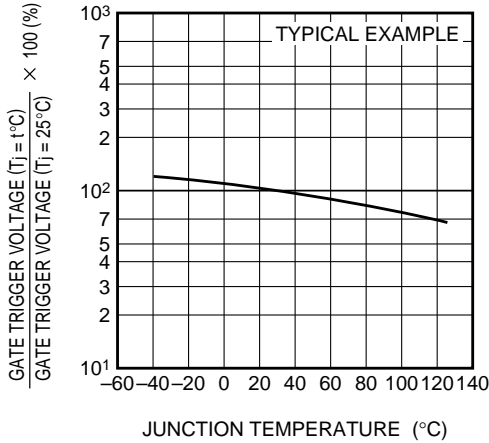
GATE CHARACTERISTICS (I, II AND III)



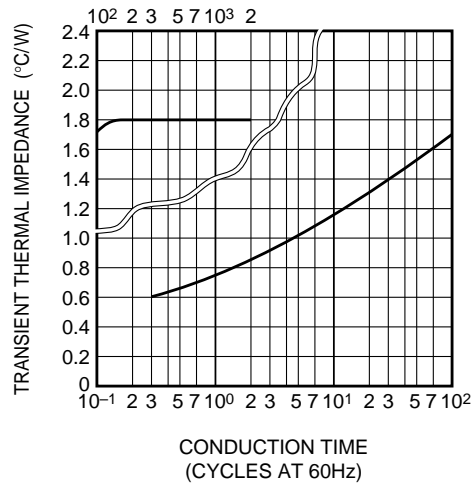
GATE TRIGGER CURRENT VS. JUNCTION TEMPERATURE



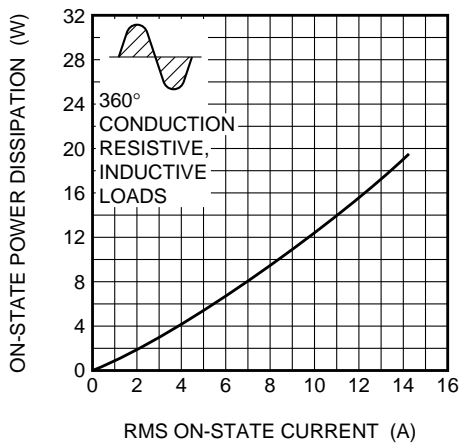
GATE TRIGGER VOLTAGE VS. JUNCTION TEMPERATURE



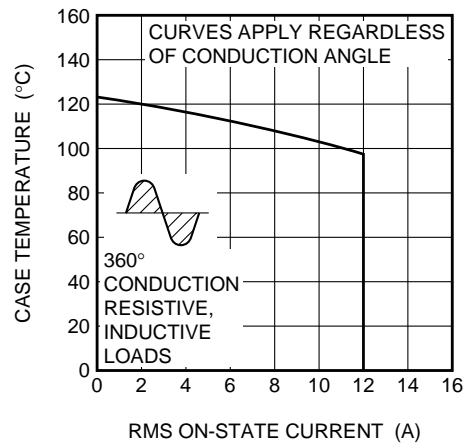
MAXIMUM TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)



MAXIMUM ON-STATE POWER DISSIPATION



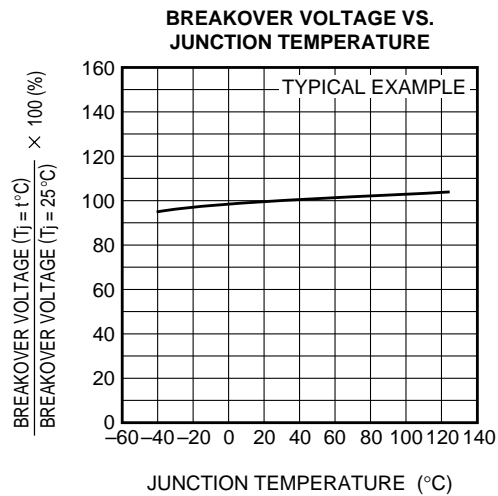
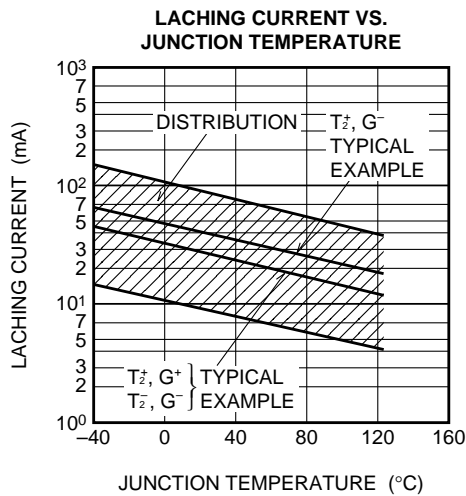
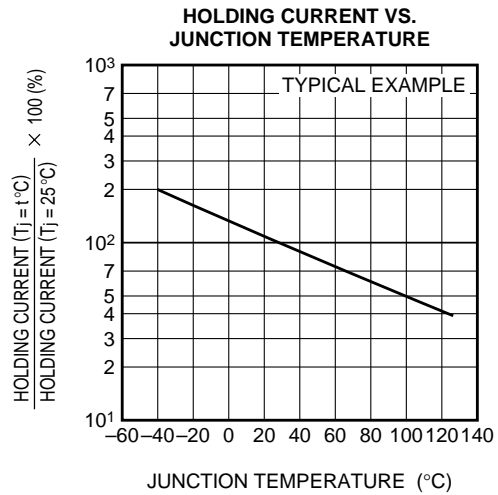
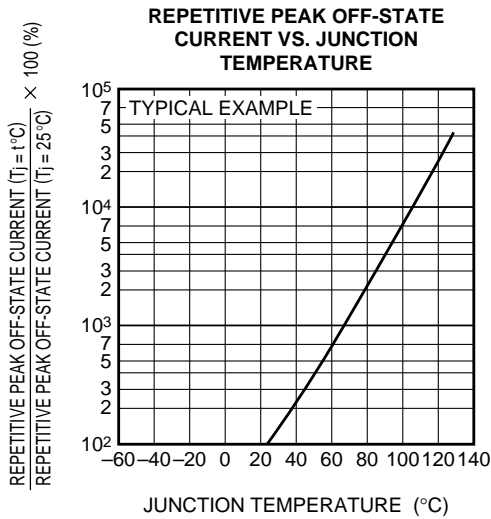
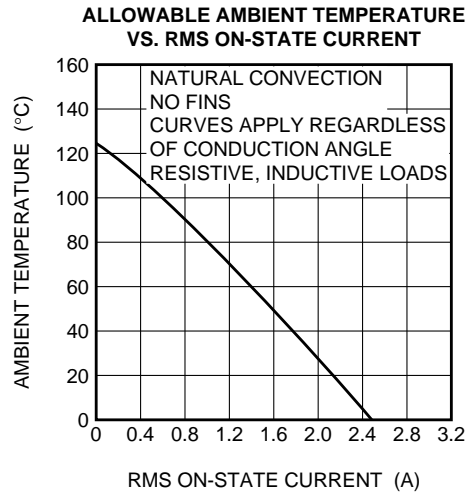
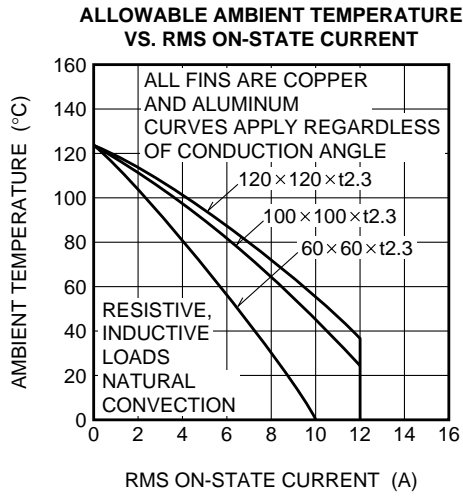
ALLOWABLE CASE TEMPERATURE VS. RMS ON-STATE CURRENT



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Refer to the page 6 as to the product guaranteed maximum junction temperature 150°C

MEDIUM POWER USE
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE



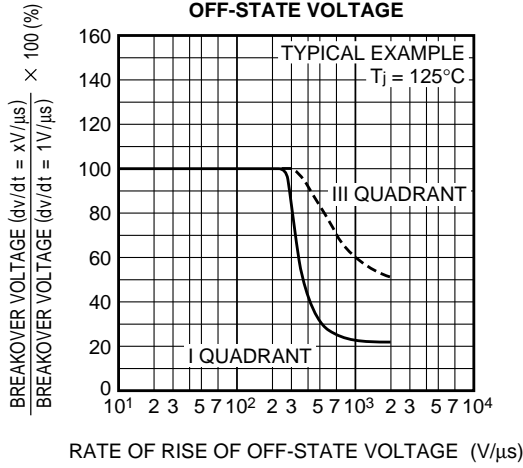
BCR12CS

MEDIUM POWER USE

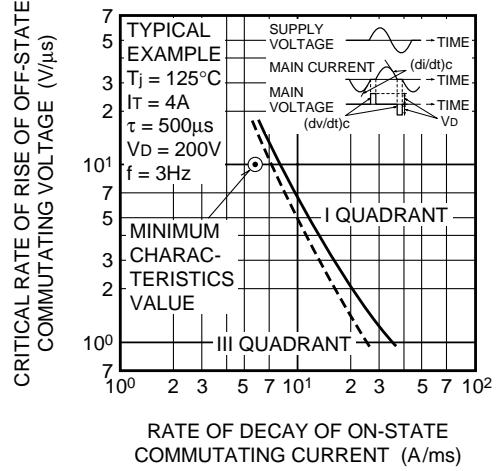
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

Refer to the page 6 as to the product guaranteed maximum junction temperature 150°C

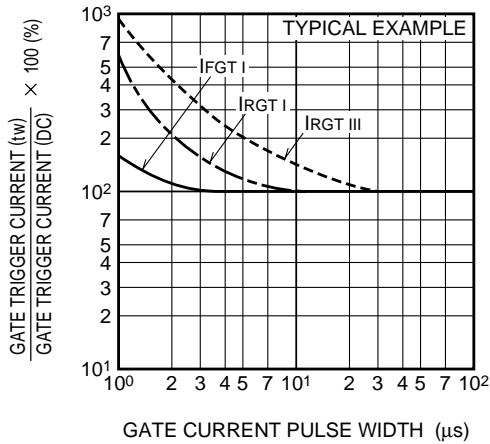
BREAKEOVER VOLTAGE VS. RATE OF RISE OF OFF-STATE VOLTAGE



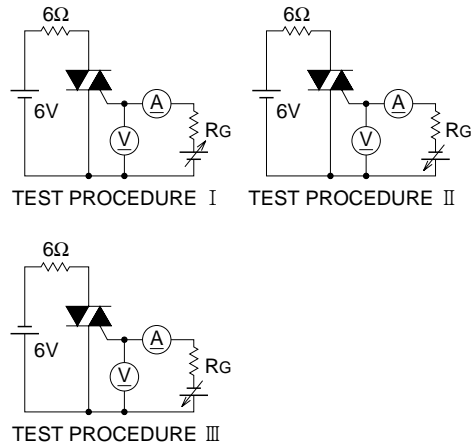
COMMUTATION CHARACTERISTICS



GATE TRIGGER CURRENT VS. GATE CURRENT PULSE WIDTH



GATE TRIGGER CHARACTERISTICS TEST CIRCUITS




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MEDIUM POWER USE

NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

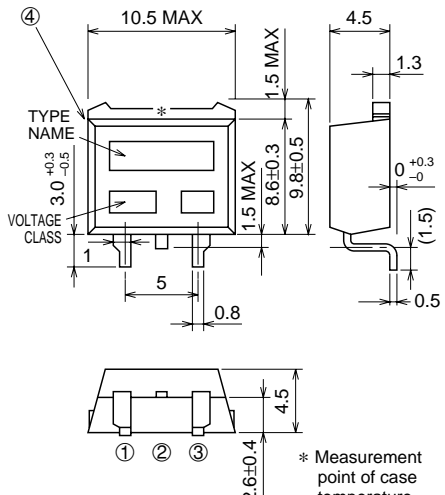
The product guaranteed maximum junction temperature 150°C (See warning.)

BCR12CS



- **IT (RMS)** **12A**
- **VDRM** **600V**
- **IFGT I , IRGT I , IRGT III** **20mA**

OUTLINE DRAWING Dimensions in mm



④ 10.5 MAX
 TYPE NAME *
 VOLTAGE CLASS 3.0 +0.3 / -0.3
 1.5 MAX
 8.6±0.3
 9.8±0.5
 4.5
 1.3
 0 +0.3 / -0
 (1.5)
 0.5
 5
 0.8
 4.5
 2.6±0.4
 * Measurement point of case temperature

② ④
 ① ③
 ① T1 TERMINAL
 ② T2 TERMINAL
 ③ GATE TERMINAL
 ④ T2 TERMINAL

TO-220S

APPLICATION

Contactless AC switches, light dimmer, electric flasher unit, control of household equipment such as TV sets · stereo · refrigerator · washing machine · infrared kotatsu · carpet · electric fan, solenoid drivers, small motor control, copying machine, electric tool, other general purpose control applications

(Warning)

1. Refer to the recommended circuit values around the triac before using.
2. Be sure to exchange the specification before using. If not exchanged, general triacs will be supplied.

MAXIMUM RATINGS

Symbol	Parameter	Voltage class		Unit
		12	600	
VDRM	Repetitive peak off-state voltage *1	600		V
VDSM	Non-repetitive peak off-state voltage *1	720		V

Symbol	Parameter	Conditions	Ratings	Unit
IT (RMS)	RMS on-state current	Commercial frequency, sine full wave 360° conduction, Tc=123°C *3	12	A
ITSM	Surge on-state current	60Hz sinewave 1 full cycle, peak value, non-repetitive	120	A
I ² t	I ² t for fusing	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	60	A ² s
PGM	Peak gate power dissipation		5	W
PG (AV)	Average gate power dissipation		0.5	W
VGM	Peak gate voltage		10	V
IGM	Peak gate current		2	A
Tj	Junction temperature		-40 ~ +150	°C
Tstg	Storage temperature		-40 ~ +150	°C
—	Weight	Typical value	1.2	g

*1. Gate open.

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The product guaranteed maximum junction temperature 150°C (See warning.)

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NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit	
			Min.	Typ.	Max.		
IDRM	Repetitive peak off-state current	T _j =150°C, V _{DRM} applied	—	—	2.0	mA	
V _{TM}	On-state voltage	T _c =25°C, I _{TM} =20A, Instantaneous measurement	—	—	1.6	V	
V _{FGT I}	Gate trigger voltage *2	T _j =25°C, V _D =6V, R _L =6Ω, R _G =330Ω	I	—	—	1.5	V
V _{RGT I}			II	—	—	1.5	V
V _{RGT III}			III	—	—	1.5	V
I _{FGT I}	Gate trigger current *2	T _j =25°C, V _D =6V, R _L =6Ω, R _G =330Ω	I	—	—	20	mA
I _{RGT I}			II	—	—	20	mA
I _{RGT III}			III	—	—	20	mA
V _{GD}	Gate non-trigger voltage	T _j =125°C/150°C, V _D =1/2V _{DRM}	0.2/0.1	—	—	V	
R _{th (j-c)}	Thermal resistance	Junction to case *3 *4	—	—	1.8	°C/W	
(dv/dt) _c	Critical-rate of rise of off-state commutating voltage *5	T _j =125°C/150°C	10/1	—	—	V/μs	

*2. Measurement using the gate trigger characteristics measurement circuit.

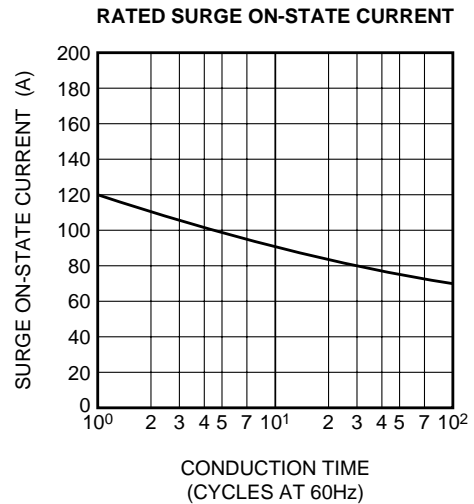
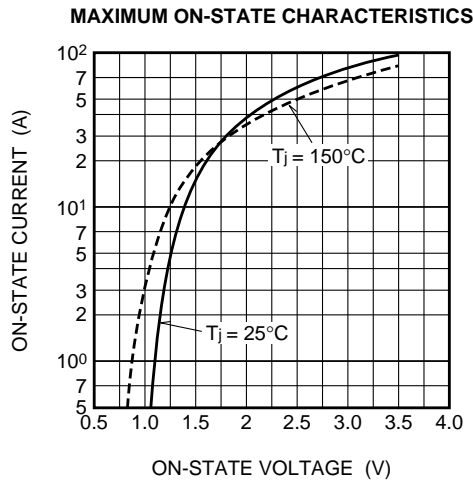
*3. Case temperature is measured on the T2 terminal.

*4. The contact thermal resistance R_{th (c-f)} in case of greasing is 1.0°C/W.

*5. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature T _j =125°C/150°C 2. Rate of decay of on-state commutating current (di/dt) _c =-6.0A/ms 3. Peak off-state voltage V _D =400V	

PERFORMANCE CURVES



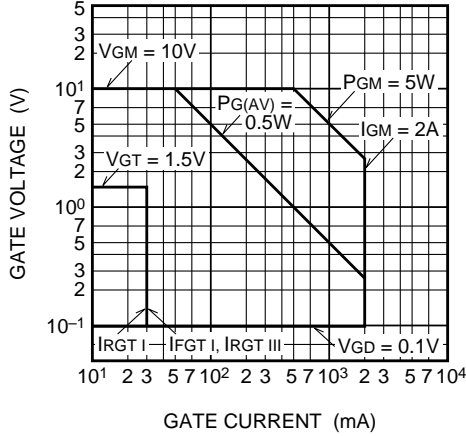
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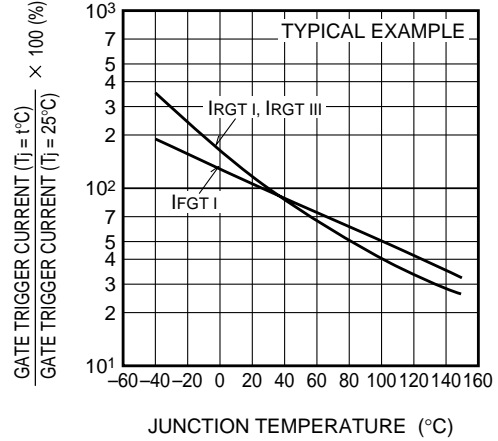
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

The product guaranteed maximum junction temperature 150°C (See warning.)

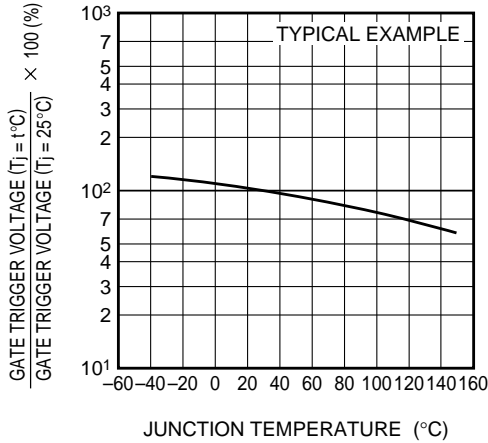
GATE CHARACTERISTICS (I, II AND III)



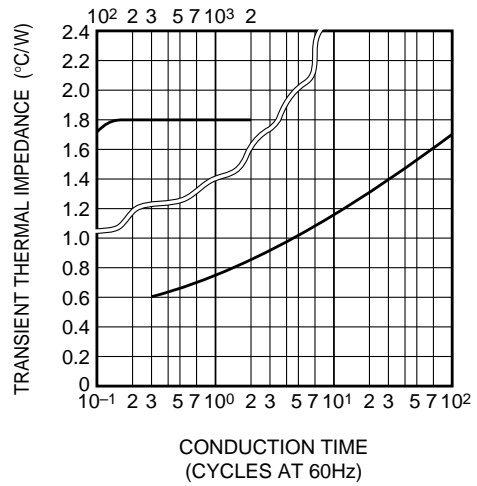
GATE TRIGGER CURRENT VS. JUNCTION TEMPERATURE



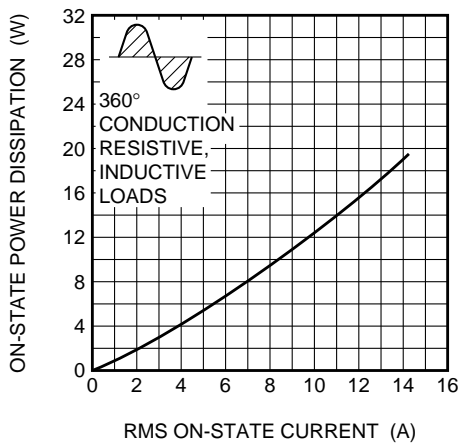
GATE TRIGGER VOLTAGE VS. JUNCTION TEMPERATURE



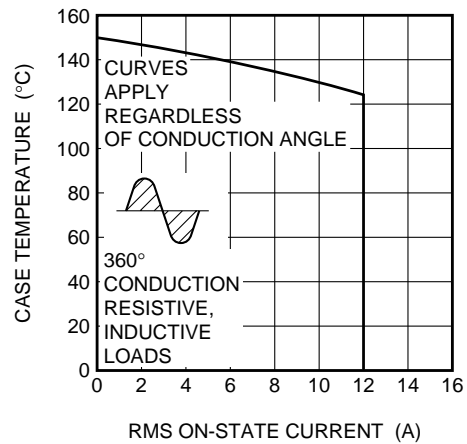
MAXIMUM TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)



MAXIMUM ON-STATE POWER DISSIPATION



ALLOWABLE CASE TEMPERATURE VS. RMS ON-STATE CURRENT

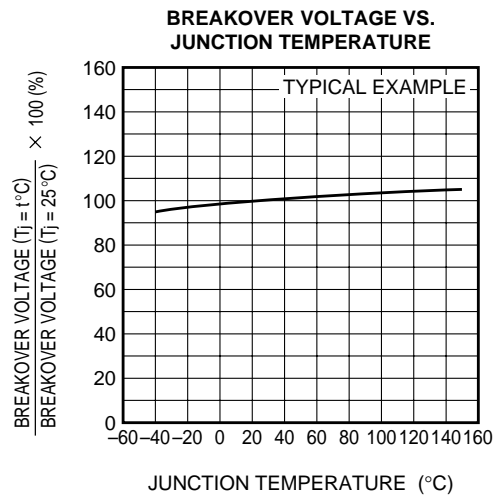
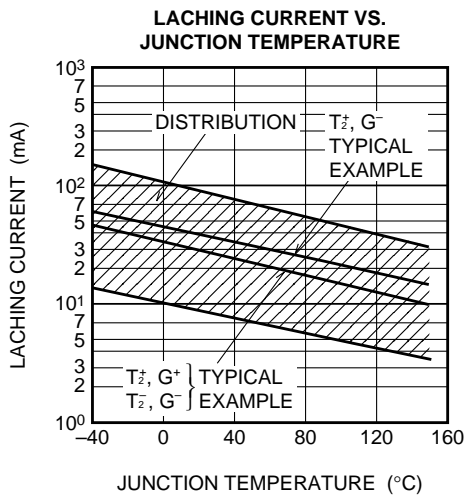
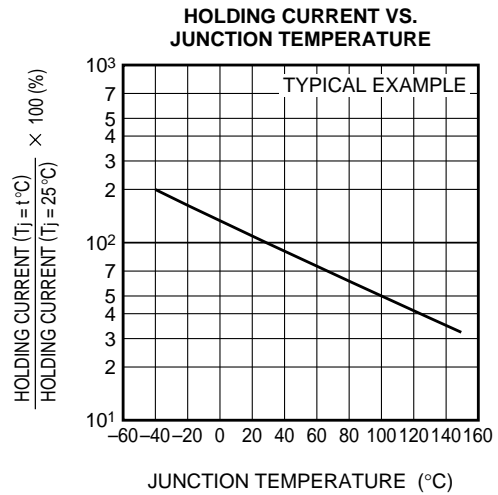
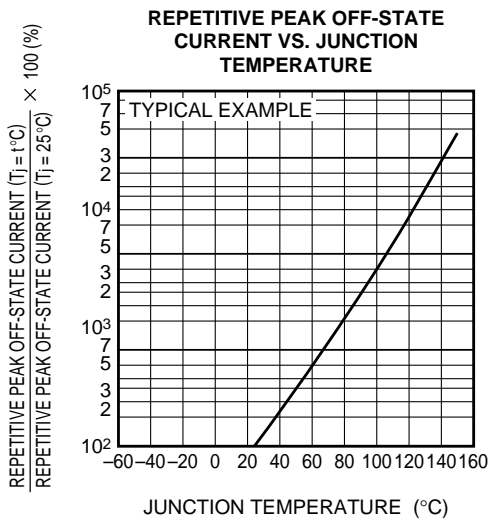
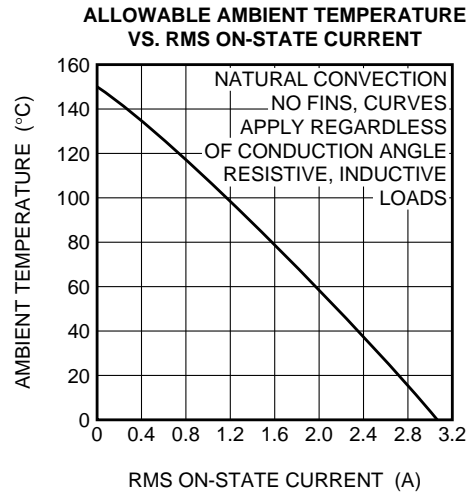
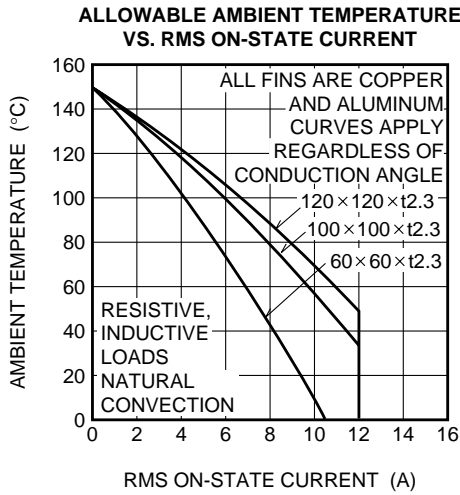


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The product guaranteed maximum junction temperature 150°C (See warning.)

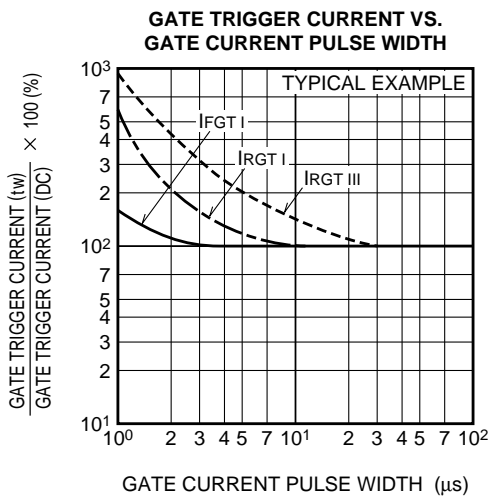
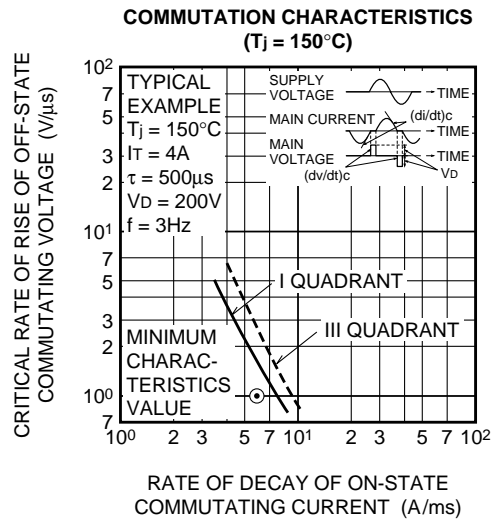
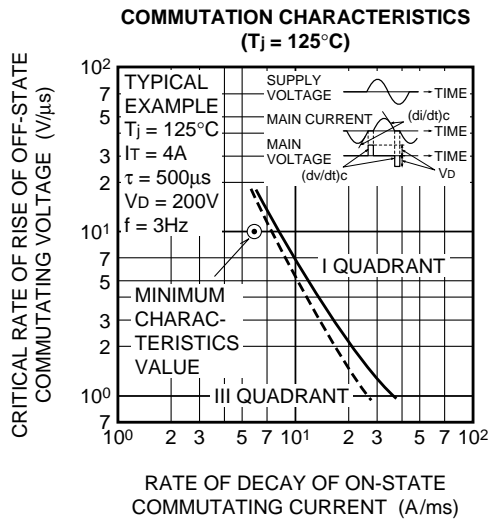
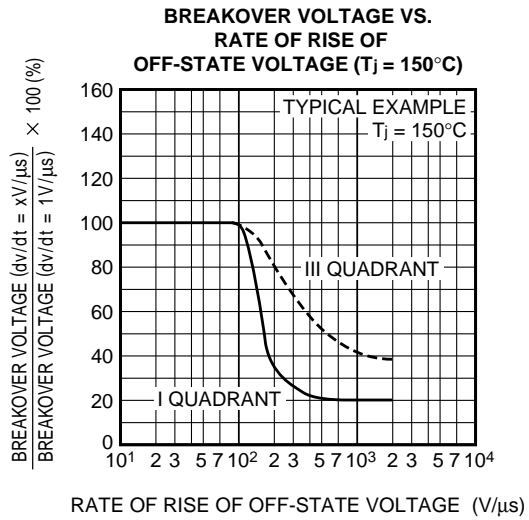
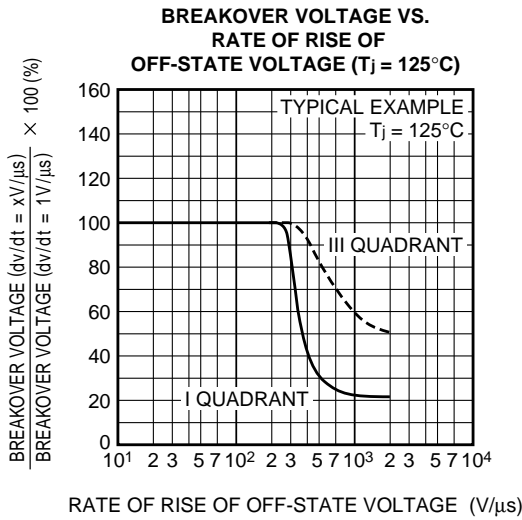


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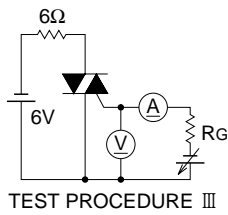
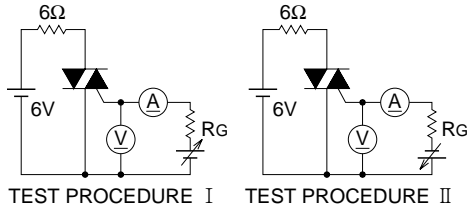


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MEDIUM POWER USE
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

GATE TRIGGER CHARACTERISTICS TEST CIRCUITS



RECOMMENDED CIRCUIT VALUES AROUND THE TRIAC

